TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

S6903G,S6903J

AC POWER CONTROL APPLICATIONS

• High Rush Current Capability

Optimal for controlling actuators where high rush current may flow.

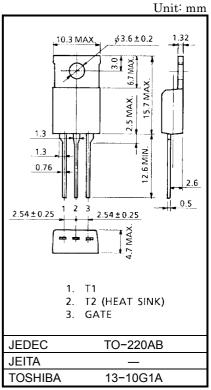
: $I_{TRM} = 120A$ (n = 100k cycle, $T_c = 45$ °C)

• R.M.S On-State Current : IT (RMS) = 20A

• Repetitive Peak Off-State Voltage: VDRM = 400V, 600V

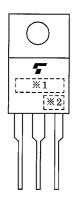
MAXIMUM RATINGS

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage	S6903G	\/	400	V	
	S6903J	V_{DRM}	600		
R.M.S On-State Current (Full Sine Waveform Tc = 100°C)		I _{T (RMS)}	20	А	
Peak One Cycle Surge On-State Current (Non-Repetitive)		l	180 (50Hz)	А	
		ITSM	200 (60Hz)	^	
Repetitive Surge On-Sta	ate Current (Note 1)	I _{TRM}	120	Α	
I ² t Limit Value		1 ² t	167	A ² s	
Critical Rate of Rise of On-State Current		di / dt	50	A / μs	
Peak Gate Power Dissip	ation	P_{GM}	5	W	
Average Gate Power Dissipation		P _{G (AV)}	0.5	W	
Peak Gate Voltage		V_{GM}	10	V	
Peak Gate Current	·	I_{GM}	2	Α	
Junction Temperature		Tj	-40~125	°C	
Storage Temperature Ra	ange	T _{stg}	-40~125	°C	



Weight: 2.0 g

MARKING



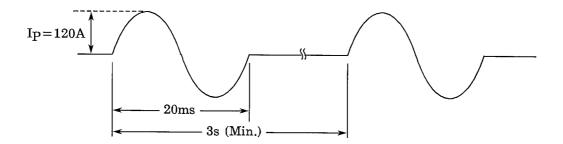
NUMBER	SYMBOL		MARK		
*1	TYPE	S6903G	S6903G		
	11171	S6903J	S6903J		
*2	Lot Number Month (Star Alph Year (Last I of the	Example 8A: January 1998 8B: February 1998 8L: December 1998			



ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} = Rated		_	_	20	μA
Gate Trigger Voltage	I	V _{GT}	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)	_	_	1.5	V
	II			T2 (+), Gate (-)	_	_	1.5	
	III			T2 (-), Gate (-)	_	_	1.5	
	IV			T2 (-), Gate (+)	_	_	_	
Gate Trigger Current	I	I _{GT}	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)	_	_	30	- mA
	II			T2 (+), Gate (-)	_	_	30	
	III			T2 (-), Gate (-)	_	_	30	
	IV			T2 (-), Gate (+)	_	_	_	
Peak On-State Voltage		V _{TM}	I _{TM} = 30A		_	_	1.6	V
Gate Non-Trigger Voltage		V_{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V
Holding Current		lΗ	V _D = 12V, I _{TM} = 2A		_	_	50	mA
Thermal Resistance		R _{th (j-c)}	Junction to Case, AC		_	_	1.0	°C/W
Critical Rate of Rise of Off-State Voltage at Commutation		(dv / dt) c	$V_{DRM} = 400V, T_j = 125^{\circ}C$ (di / dt) c = -8.7Å / ms		10	_	_	V /µs

Note 1: Repetitive Surge On-State Current



 I_P = 120A (f = 50Hz) at Tc = 45°C

Max. Repetitive Number of cycle n = 100k cycle (Repetitive cycle T = 3s Min.)

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